

Features

- Peak Output Current : $IOP = \pm 1.0A$ (max)
- Threshold Input Current: IFLH = 5 mA (max)
- Common mode transient immunity : ±25kV/µs (min)
- **RoHS and REACH Compliance**
- MSL class 1
- **Regulatory Approvals**
 - UL UL1577 (E364000) \checkmark
 - ✓ VDE - EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898(14001104999) ✓
 - IEC62368 (FI/41119) 1

Description

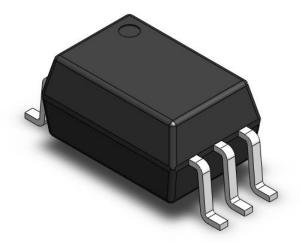
The CTS314 consists of a GaAsP LED optically coupled to an integrated circuit with a power output stage. This optocoupler is ideally suited for driving power IGBTs and MOSFETs used in motor control inverter applications. The high operating voltage range of the output stage provides the drive voltages required by gate controlled devices.

Applications

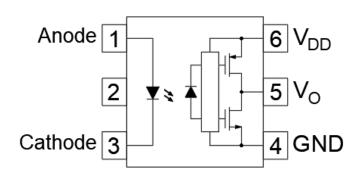
- Isolated IGBT/Power MOSFET gate drive
- Industrial Inverter
- AC brushless and DC motor drives
- Induction Heating

Package Outline





Note: Different lead forming options available. See package dimension.



Truth Table

| LED | V _{cc} -V _{EE} Positive Going | V _{cc} -V _{EE} Negative Going | Output |
|-----|--|--|------------|
| Off | 0 to 30 V | 0 to 30V | Low |
| On | 0 to 11.0V | 0 to 9.5V | Low |
| On | 11.0 to 13.5V | 9.5 to 12V | Transition |
| On | 13.5 to 30V | 12 to 30V | High |



Absolute Maximum Ratings $T_A = 25^{\circ}C$, unless otherwise specified

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameters | Ratings | Units | Notes |
|----------|---|------------|------------------|-------|
| Viso | Isolation voltage (AC, 1 minute, 40 ~ 60% R.H.) | 5000 | V _{RMS} | 1 |
| Topr | Operating temperature | -40 ~ +100 | 0C | |
| Tstg | Storage temperature | -55 ~ +125 | 0C | |
| Tsol | Soldering temperature (For 10 seconds) | 260 | 0C | 2 |
| Ρτ | Total Power Dissipation | 300 | mW | |
| Emitter | | - | | |
| lF | Forward current | 25 | mA | |
| IFP | Peak forward current (50% duty, 1ms P.W) | 1 | А | |
| VR | Reverse voltage | 5 | V | |
| Detector | | | · | |
| Po | Output Power dissipation | 250 | mW | |
| VO(PEAK) | Peak Output Voltage | 35 | V | 3 |
| Іорн | Output High Peak Current | 1 | А | 4 |
| IOPL | Output Low Peak Current | 1 | А | 4 |
| Vcc | Supply voltage | 35 | V | |

Notes

1. AC for 1 minute, $RH = 40 \sim 60\%$.

- 2. For 10 second peak
- 3. The $V_{O(\text{PEAK})}$ voltage CAN NOT BE high than $V_{\text{CC}}.$
- 4. The I₀ maximum pulse width = 10 us, maximum duty cycle = 0.2%.



Electrical Characteristics

Over recommended operating conditions TA = -40 to 100 °C. Typical values are measured at $V_{CC}=30V$, $V_{EE}=$ GND, $T_A = 25^{\circ}C$ (unless

otherwise stated)

Emitter Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|---------------------------|--|-----------------------|-----|------|-----|-------|-------|
| VF | Forward Voltage | I _F = 10mA | - | 1.4 | 1.8 | V | |
| VR | Reverse Voltage | I _R = 10μA | 5.0 | - | - | V | |
| $\Delta V_F / \Delta T_A$ | Temperature coefficient of forward voltage | I _F = 10mA | - | -1.7 | - | mV/°C | |

Detector Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|--------|---------------------------|-----------------|-----|-----|-----|------------|-------|
| lcc∟ | Logic Low Supply Current | IF= 0mA | - | 1.5 | 3 | ~ ^ | |
| Іссн | Logic High Supply Current | IF= 10mA | - | 1.5 | 3 | mA | |

Transfer Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|---------------------|----------------------------------|--|---------|---------|------|-------|-------|
| Vон | High Level Output Voltage | I _F = 10mA, I _O = -100mA | Vcc-0.6 | Vcc-0.4 | - | V | |
| Vol | Low Level Output Voltage | I _F = 0mA, I _O = 100mA | - | 0.25 | 0.4 | V | |
| | High Lovel Output Current | Vo= Vcc-2V | - | - | -0.3 | | 1 |
| IOPH | High Level Output Current | Vo= Vcc-4V | - | - | -0.9 | A | 1 |
| 1 | Low Level Output Current | V _O = V _{EE} +2V | 0.3 | - | - | A | 1 |
| OPL | | Vo= VEE+4V | 0.9 | - | - | | 1 |
| IFLH | Input Threshold Current | I ₀ = 0mA, V ₀ > 5V | - | 1.4 | 5.0 | mA | |
| Vfhl | Input Threshold Voltage | I ₀ = 0mA, V ₀ < 5V | 0.8 | - | - | V | |
| VUVLO+ | Under Voltage Lockout | IO= 10mA, VO> 5V | 6.9 | 7.8 | 8.7 | V | |
| Vuvlo- | Threshold | IO= 10mA, VO< 5V | 5.9 | 6.7 | 7.5 | V | |
| UVLO _{HYS} | Under Voltage Lockout Hysteresis | | - | 1.1 | - | V | |

Notes

1. The I₀ maximum pulse width = 10 us, maximum duty cycle = 0.2%.



Electrical Characteristics

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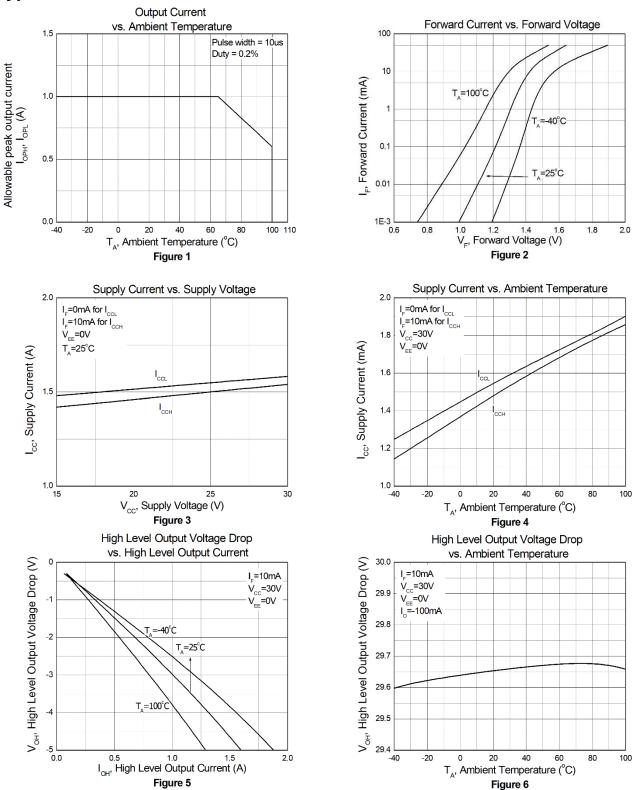
Switching Characteristics

| Symbol | Parameters | Test C | onditions | Min | Тур | Max | Units | Notes |
|----------------|-------------------------------|---|----------------------|------|-----|-----|-------|-------|
| TPHL | High to Low Propagation Delay | | | 100 | 160 | 300 | ns | |
| TPLH | Low to High Propagation Delay | | | 100 | 130 | 300 | ns | |
| PWD | Pulse Width Distortion | Rg = 47Ω, Cg | = 3 nF, | - | 30 | - | ns | |
| | Propagation Delay Difference | f = 10 kHz, Du | ity = 50%, | | | | | |
| PDD | Between Any Two Parts or | I _F = 10mA, | | -100 | - | 100 | ns | |
| | Channels | Vcc = 30V | | | | | | |
| tr | Rise Time | | | - | 20 | 100 | ns | |
| t _f | Fall Time | | | - | 20 | 100 | ns | |
| [СМн] | Common Mode Transient High | V _{CC} = 30V, T _A = 25 ^o C, | IF= 7.5mA | 25 | - | - | kV/μs | |
| CM∟ | Common Mode Transient Low | V _{CM} = 1.5kV | I _F = 0mA | 25 | - | - | kV/μs | |

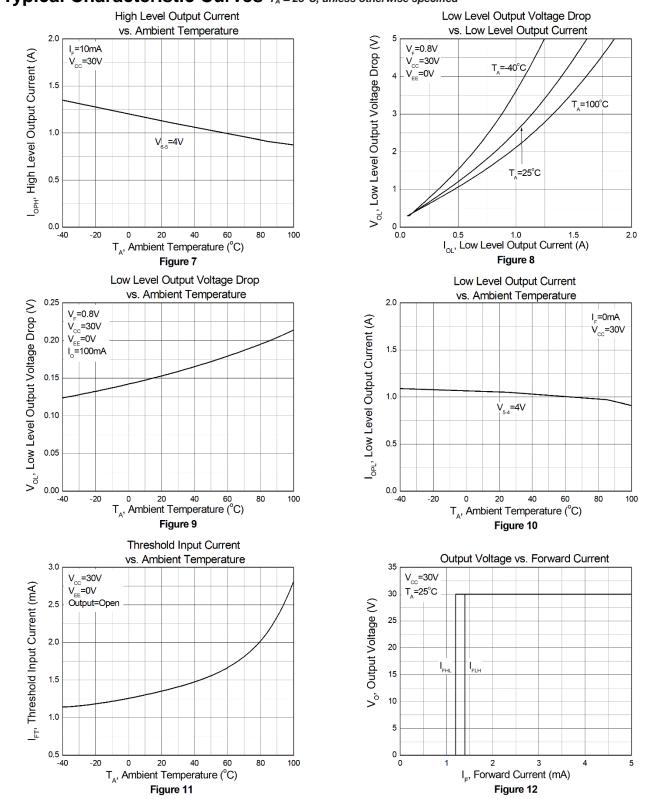


CTS314

Typical Characteristic Curves $T_A = 25^{\circ}C$, unless otherwise specified



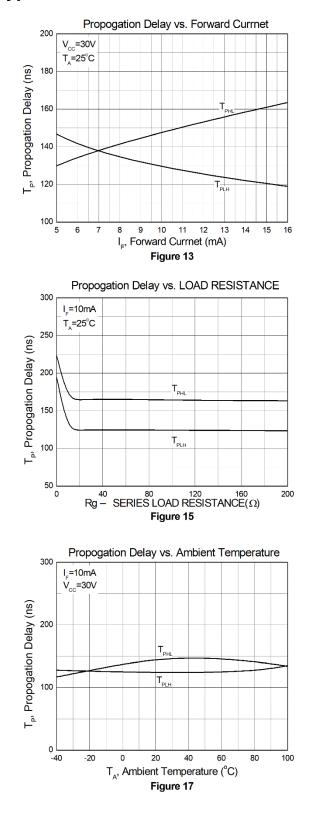


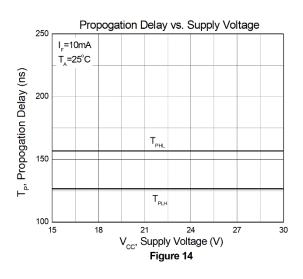


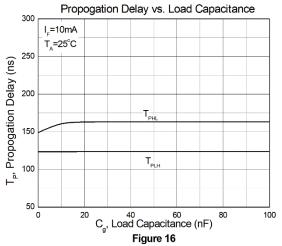
Typical Characteristic Curves $T_A = 25^{\circ}C$, unless otherwise specified



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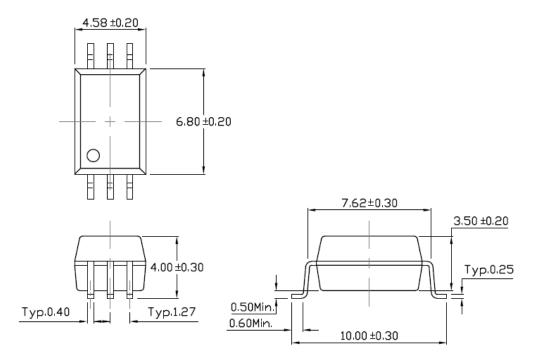




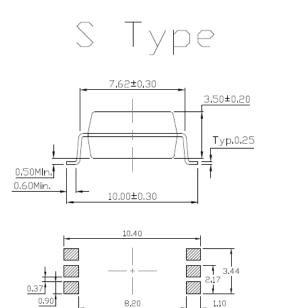


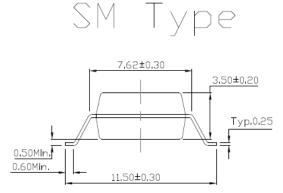
Package Dimension Dimensions in mm unless otherwise stated

Surface Mount Lead Forming



Forming Option Dimensions in mm unless otherwise stated









CTS314

1.0A MOSFET/IGBT Gate Driver Optocoupler

: Denotes "CT Micro"

: One Digit Year Code

: Manufacturing Code

: VDE Safety Mark Option (Blank or V)

: Part Number

WW : Two Digit Work Week

Note: CT

314

V

Y

Κ

Marking Information



Ordering Information

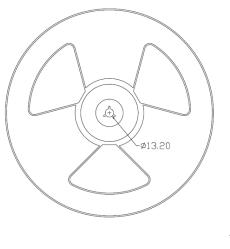
CTS314(V)(Y)(Z)

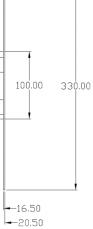
- CT = Denotes "CT Micro"
- S314 = Part Number
 - V = VDE Safety Mark Option (Blank or V)
 - Y = Lead Form Option (S or SM)
- Z = Tape and Reel Option (T1 or T2)

| Ζ = | z = rape and Reel Option (11 of 12) | | | | | | |
|--------|--|-----------------|--|--|--|--|--|
| Option | Description | Quantity | | | | | |
| T1 | Surface Mount Lead Forming with Option 1 Taping | 1500 Units/Reel | | | | | |
| T2 | Surface Mount Lead Forming with Option 2 Taping | 1500 Units/Reel | | | | | |
| M(T1) | Surface Mount (Gullwing) Lead Forming with Option 1 Taping | 1500 Units/Reel | | | | | |
| M(T2) | Surface Mount (Gullwing) Lead Forming with Option 2 Taping | 1500 Units/Reel | | | | | |

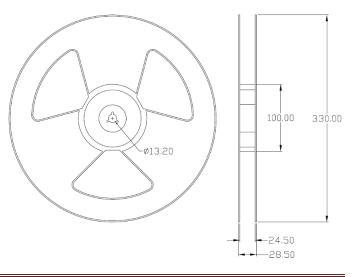
Reel Dimension All dimensions are in mm, unless otherwise stated

Option S(T1/T2)





Option M(T1/T2)

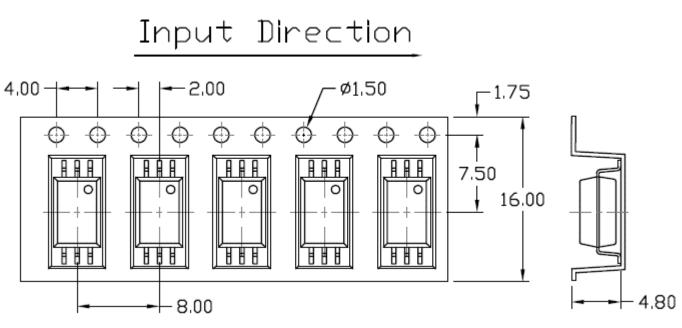




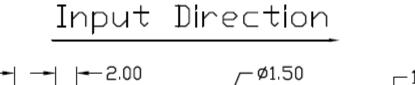
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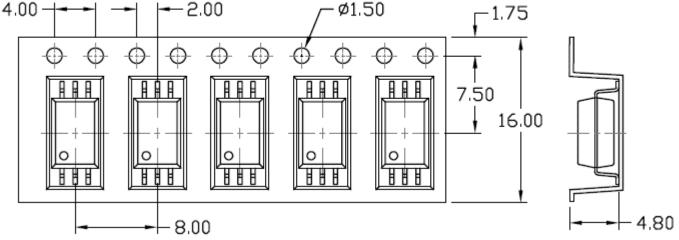
Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option S(T1)



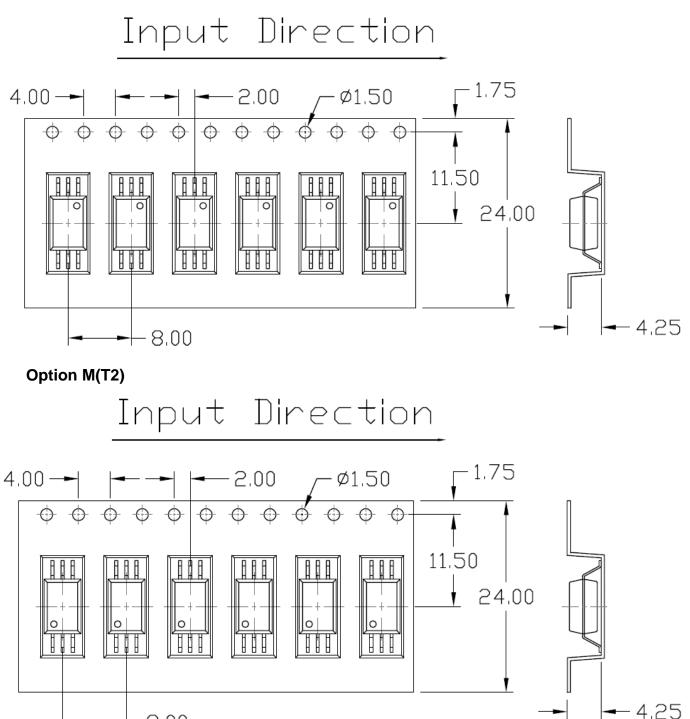
Option S(T2)







Option M(T1)



- 8,00



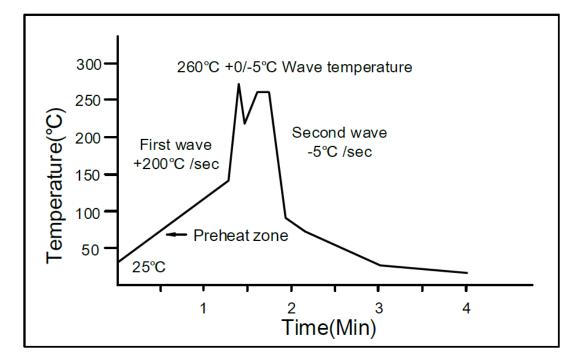
Solderability spec (Follow the JEDEC standard JESD22-B102)

Reflow Soldering: Immersed surface, other than the end of pin as cut-surface, must be covered by solder.

Solder-Bath: More than 95% of the electrode must be covered with solder.

Wave soldering (Follow the JEDEC standard JESD22-A111)

One time soldering is recommended within the condition of temperature. Temperature: 260+0/-5°C. Time: 10 sec. Preheat temperature: 25 to 140°C. Preheat time: 30 to 80 sec.

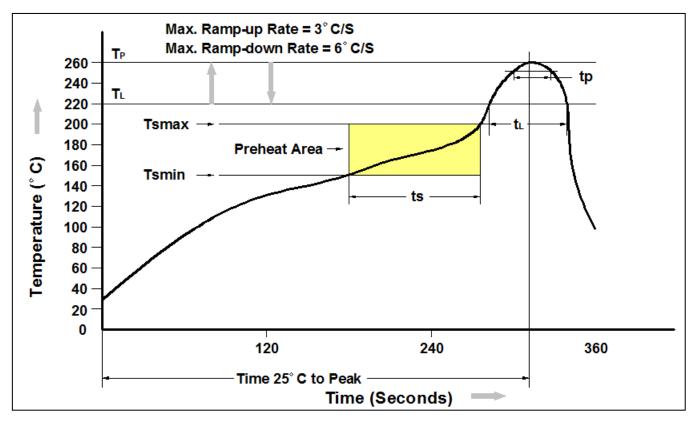


Iron soldering (Follow the standard MIL-STD 202G, Method 210F)

Allow single lead soldering in every single process. One time soldering is recommended. Temperature: 350±10°C Time: 5 sec max.



Reflow Profile (Follow the JEDEC standard J-STD-020)



| Profile Feature | Pb-Free Assembly Profile |
|---|--------------------------|
| Temperature Min. (Tsmin) | 150°C |
| Temperature Max. (Tsmax) | 200°C |
| Time (ts) from (Tsmin to Tsmax) | 60-120 seconds |
| Ramp-up Rate (t∟ to t _P) | 3°C/second max. |
| Liquidous Temperature (TL) | 217°C |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate $(T_P \text{ to } T_L)$ | 6°C/second max |
| Time 25°C to Peak Temperature | 8 minutes max. |



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